

Sunghyun Kim

List of Publications by Year in descending order

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30
papers

1,371
citations

471371

17
h-index

454834

30
g-index

32
all docs

32
docs citations

32
times ranked

2171
citing authors

#	ARTICLE	IF	CITATIONS
1	Point defect engineering in thin-film solar cells. <i>Nature Reviews Materials</i> , 2018, 3, 194-210.	23.3	275
2	Identification of Killer Defects in Kesterite Thin-Film Solar Cells. <i>ACS Energy Letters</i> , 2018, 3, 496-500.	8.8	130
3	Promotion of electrochemical oxygen evolution reaction by chemical coupling of cobalt to molybdenum carbide. <i>Applied Catalysis B: Environmental</i> , 2018, 227, 340-348.	10.8	110
4	Upper limit to the photovoltaic efficiency of imperfect crystals from first principles. <i>Energy and Environmental Science</i> , 2020, 13, 1481-1491.	15.6	107
5	Prediction of Green Phosphorus with Tunable Direct Band Gap and High Mobility. <i>Journal of Physical Chemistry Letters</i> , 2017, 8, 4627-4632.	2.1	101
6	In situ observation of picosecond polaron self-localisation in Fe_2O_3 photoelectrochemical cells. <i>Nature Communications</i> , 2019, 10, 3962.	5.8	93
7	Computational search for direct band gap silicon crystals. <i>Physical Review B</i> , 2014, 90, .	1.1	63
8	Ab initio materials design using conformational space annealing and its application to searching for direct band gap silicon crystals. <i>Computer Physics Communications</i> , 2016, 203, 110-121.	3.0	55
9	Lone-pair effect on carrier capture in $\text{Cu}_2\text{ZnSnS}_4$ solar cells. <i>Journal of Materials Chemistry A</i> , 2019, 7, 2686-2693.	5.2	55
10	Intrinsic doping limit and defect-assisted luminescence in Cs_4PbBr_6 . <i>Journal of Materials Chemistry A</i> , 2019, 7, 20254-20261.	5.2	48
11	Dipole-allowed direct band gap silicon superlattices. <i>Scientific Reports</i> , 2015, 5, 18086.	1.6	37
12	Giant Huang-Rhys Factor for Electron Capture by the Iodine Interstitial in Perovskite Solar Cells. <i>Journal of the American Chemical Society</i> , 2021, 143, 9123-9128.	6.6	37
13	Anharmonic lattice relaxation during nonradiative carrier capture. <i>Physical Review B</i> , 2019, 100, .	1.1	34
14	Assessing the defect tolerance of kesterite-inspired solar absorbers. <i>Energy and Environmental Science</i> , 2020, 13, 3489-3503.	15.6	28
15	Quick-start guide for first-principles modelling of point defects in crystalline materials. <i>JPhys Energy</i> , 2020, 2, 036001.	2.3	22
16	Stability and Segregation of B and P Dopants in Si/SiO_2 Core-Shell Nanowires. <i>Nano Letters</i> , 2012, 12, 5068-5073.	4.5	19
17	Role of electron-phonon coupling and thermal expansion on band gaps, carrier mobility, and interfacial offsets in kesterite thin-film solar cells. <i>Applied Physics Letters</i> , 2018, 112, .	1.5	19
18	Semimetallic carbon allotrope with a topological nodal line in mixed sp^2 - sp^3 bonding networks. <i>NPG Asia Materials</i> , 2017, 9, e361-e361.	3.8	18

#	ARTICLE	IF	CITATIONS
19	Open-circuit voltage deficit in Cu ₂ ZnSnS ₄ solar cells by interface bandgap narrowing. Applied Physics Letters, 2018, 113, 212103.	1.5	16
20	Low Barrier for Exciton Self-Trapping Enables High Photoluminescence Quantum Yield in Cs ₃ Cu ₂ I ₅ . Journal of Physical Chemistry Letters, 2021, 12, 8447-8452.	2.1	16
21	Opposing effects of stacking faults and antisite domain boundaries on the conduction band edge in kesterite quaternary semiconductors. Physical Review Materials, 2018, 2, .	0.9	15
22	Boron Triangular Kagome Lattice with Half-Metallic Ferromagnetism. Scientific Reports, 2017, 7, 7279.	1.6	14
23	CarrierCapture.jl: Anharmonic Carrier Capture. Journal of Open Source Software, 2020, 5, 2102.	2.0	14
24	Direct band gap carbon superlattices with efficient optical transition. Physical Review B, 2016, 93, .	1.1	12
25	Crystal Engineering of Bi ₂ WO ₆ to Polar Aurivillius-Phase Oxyhalides. Journal of Physical Chemistry C, 2019, 123, 29155-29161.	1.5	12
26	<i>Ab initio</i> calculation of the detailed balance limit to the photovoltaic efficiency of single p-n junction kesterite solar cells. Applied Physics Letters, 2021, 118, .	1.5	7
27	Stability and electronic properties of planar defects in quaternary I ² -II-IV-VI ₄ semiconductors. Journal of Applied Physics, 2018, 124, 165705.	1.1	5
28	Finite-size supercell correction scheme for charged defects in one-dimensional systems. Physical Review B, 2014, 90, .	1.1	4
29	Three-dimensional buckled honeycomb boron lattice with vacancies as an intermediate phase on the transition pathway from I [±] -B to I ³ -B. NPG Asia Materials, 2017, 9, e400-e400.	3.8	4
30	Design of Dipole-Allowed Direct Band Gaps in Ge/Sn Core-Shell Nanowires. Journal of Physical Chemistry C, 2016, 120, 28169-28175.	1.5	1